Preferred Device

# Complementary Power Transistors

# **DPAK For Surface Mount Applications**

Designed for general purpose power and switching such as output or driver stages in applications such as switching regulators, converters, and power amplifiers.

### Features

- Pb–Free Packages are Available
- Lead Formed for Surface Mount Application in Plastic Sleeves (No Suffix)
- Straight Lead Version in Plastic Sleeves ("-1" Suffix)
- Lead Formed Version in 16 mm Tape and Reel for Surface Mount ("T4" Suffix)
- Electrically Similar to Popular D44H/D45H Series
- Low Collector Emitter Saturation Voltage –
   V<sub>CE(sat)</sub> = 1.0 Volt Max @ 8.0 Amperes
- Fast Switching Speeds
- Complementary Pairs Simplifies Designs
- Epoxy Meets UL 94, V-0 @ 0.125 in
- ESD Ratings: Human Body Model, 3B > 8000 V
   Machine Model, C > 400 V

# **MAXIMUM RATINGS**

Rating	Symbol	Max	Unit
Collector–Emitter Voltage	V <sub>CEO</sub>	80	Vdc
Emitter-Base Voltage	$V_{EB}$	5	Vdc
Collector Current - Continuous Peak	Ic	8 16	Adc
Total Power Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	P <sub>D</sub>	20 0.16	W/°C
Total Power Dissipation* @ T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	1.75 0.014	W/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	6.25	°C/W
Thermal Resistance, Junction-to-Ambient*	$R_{\theta JA}$	71.4	°C/W
Lead Temperature for Soldering	TL	260	°C

<sup>\*</sup>These ratings are applicable when surface mounted on the minimum pad sizes recommended.



# ON Semiconductor

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# SILICON POWER TRANSISTORS 8 AMPERES 80 VOLTS 20 WATTS

# MARKING DIAGRAMS

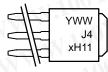


DPAK CASE 369C STYLE 1





DPAK-3 CASE 369D STYLE 1



Y = Year WW = Work Week x = 4 or 5

#### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 3 of this data sheet.

**Preferred** devices are recommended choices for future use and best overall value.

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### **ELECTRICAL CHARACTERISTICS** (T<sub>C</sub> = 25°C unless otherwise noted)

	<i>&gt;</i>	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS		110	07.			
Collector–Emitter Sustaining Voltage (I <sub>C</sub> = 30 mA, I <sub>B</sub> = 0)		V <sub>CEO(sus)</sub>	80	Co	_	Vdc
Collector Cutoff Current $(V_{CE} = Rated V_{CEO}, V_{BE} = 0)$	WTI	I <sub>CES</sub>	100	Z.E.	10	μА
Emitter Cutoff Current (V <sub>EB</sub> = 5 Vdc)	WILL	I <sub>EBO</sub>	10	NT.C	50	μΑ
ON CHARACTERISTICS	Ohr.		100		CO.	
Collector–Emitter Saturation Voltage (I <sub>C</sub> = 8 Adc, I <sub>B</sub> = 0.4 Adc)	COM.	V <sub>CE(sat)</sub>	11-1	002	(.10	Vdc
Base–Emitter Saturation Voltage (I <sub>C</sub> = 8 Adc, I <sub>B</sub> = 0.8 Adc)	COM	V <sub>BE(sat)</sub>	TH.	Too	1.5	Vdc
DC Current Gain (V <sub>CE</sub> = 1 Vdc, I <sub>C</sub> = 2 Adc)	V.COM.	h <sub>FE</sub>	60	1.70	Ţ.	COD
DC Current Gain (V <sub>CE</sub> = 1 Vdc, I <sub>C</sub> = 4 Adc)	OY.COM.		40	N-7	003	CO
DYNAMIC CHARACTERISTICS	COM	<b>*</b> 1	1	W.	1.0	47 C
Collector Capacitance (V <sub>CB</sub> = 10 Vdc, f <sub>test</sub> = 1 MHz)	MJD44H11 MJD45H11	C <sub>cb</sub>	<u> </u>	130 230	100	pF
Gain Bandwidth Product (I <sub>C</sub> = 0.5 Adc, V <sub>CE</sub> = 10 Vdc, f = 20 MHz)	MJD44H11 MJD45H11	TW fT	_	50 40	12.1	MHz
SWITCHING TIMES	X 100 Y	1.7.1	•		-TXX	100
Delay and Rise Times (I <sub>C</sub> = 5 Adc, I <sub>B1</sub> = 0.5 Adc)	MJD44H11 MJD45H11	$t_d + t_r$	_ _	300 135		ns
Storage Time $(I_C = 5 \text{ Adc}, I_{B1} = I_{B2} = 0.5 \text{ Adc})$	MJD44H11 MJD45H11	o t <sub>s</sub>		500 500	N-M	ns
Fall Time $(I_C = 5 \text{ Adc}, I_{B1} = I_{B2} = 0.5 \text{ Adc})$	MJD44H11 MJD45H11	CONT	N N	140 100	-	ns

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### **ORDERING INFORMATION**

Device	Package Type	Package	Shipping <sup>†</sup>
MJD44H11	DPAK	369C	75 Units / Ra
MJD44H11-001	DPAK-3	369D	75 Units / Ra
MJD44H11G	DPAK (Pb-Free)	369C	75 Units / Ra
MJD44H11RL	DPAK	369C	1800 Tape & F
MJD44H11T4	DPAK	369C	2500 Tape & F
MJD44H11T4G	DPAK (Pb-Free)	369C	2500 Tape & I
MJD44H11T5	DPAK	369C	2500 Tape & F
MJD45H11	DPAK	369C	75 Units / R
MJD45H11-001	DPAK-3	369D	75 Units / R
MJD45H11G	DPAK (Pb-Free)	369C	75 Units / R
MJD45H11RL	DPAK	369C	1800 Tape & F
MJD45H11T4	DPAK	369C	2500 Tape & F
MJD45H11T4G	DPAK (Pb-Free)	369C	2500 Tape & F

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D. WWW.100Y.COM.TV

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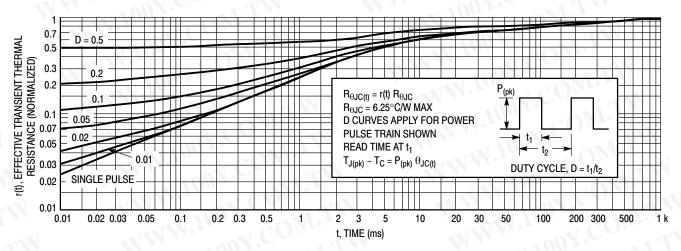


Figure 1. Thermal Response

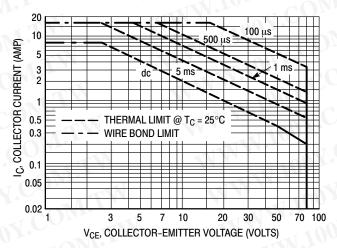


Figure 2. Maximum Forward Bias Safe Operating Area

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate  $I_C - V_{CE}$  limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 2 is based on  $T_{J(pk)} = 150^{\circ} C$ ;  $T_{C}$  is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided  $T_{J(pk)} \le 150^{\circ} C$ .  $T_{J(pk)}$  may be calculated from the data in Figure 1. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

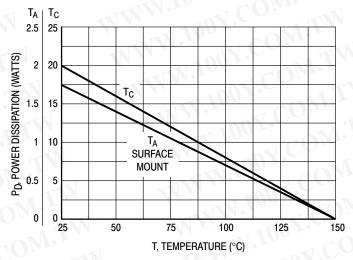


Figure 3. Power Derating

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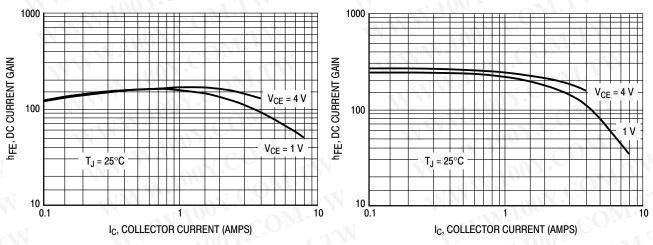


Figure 4. MJD44H11 DC Current Gain

Figure 5. MJD45H11 DC Current Gain

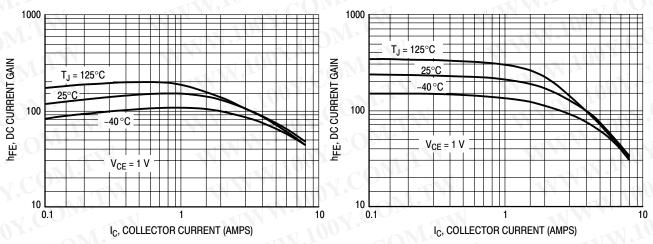


Figure 6. MJD44H11 Current Gain versus Temperature

Figure 7. MJD45H11 Current Gain versus Temperature

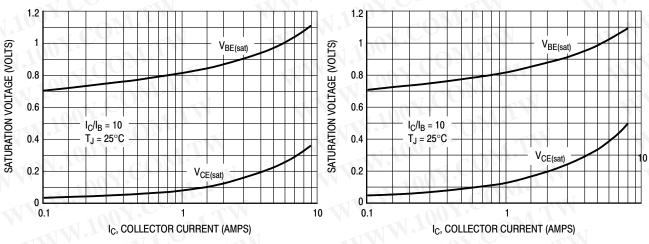


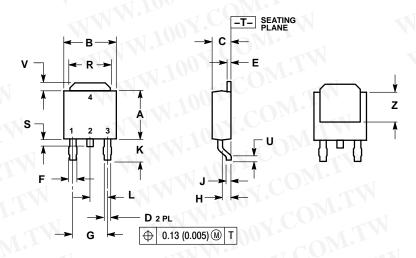
Figure 8. MJD44H11 On-Voltages

Figure 9. MJD45H11 On-Voltages

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#### PACKAGE DIMENSIONS

## **DPAK** CASE 369C **ISSUE O**



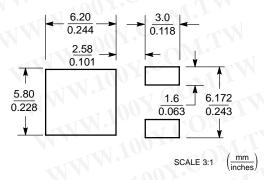
#### NOTES:

- OTES.
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.

	INC	HES	MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.235	0.245	5.97	6.22	
В	0.250	0.265	6.35	6.73	
С	0.086	0.094	2.19	2.38	
D	0.027	0.035	0.69	0.88	
E	0.018	0.023	0.46	0.58	
F	0.037	0.045	0.94	1.14	
O	0.180 BSC		4.58 BSC		
Н	0.034	0.040	0.87	1.01	
J	0.018	0.023	0.46	0.58	
K	0.102	0.114	2.60	2.89	
L	0.090	0.090 BSC		BSC	
R	0.180	0.215	4.57	5.45	
S	0.025	0.040	0.63	1.01	
U	0.020	( L	0.51		
V	0.035	0.050	0.89	1.27	
Z	0.155		3.93	7	

STYLE 1: PIN 1. BASE 2. COLLECTOR 3. EMITTER 4. COLLECTOR

# **SOLDERING FOOTPRINT\***

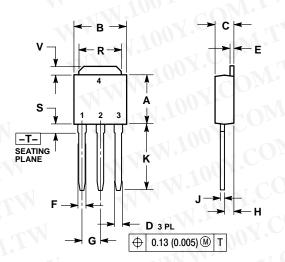


\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

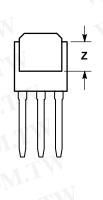
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#### PACKAGE DIMENSIONS

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#### NOTES:

- DIMENSIONING AND TOLERANCING PER
- ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.

	INCHES		HES MILLIMETER	
DIM	MIN	MAX	MIN	MAX
Α	0.235	0.245	5.97	6.35
В	0.250	0.265	6.35	6.73
С	0.086	0.094	2.19	2.38
D	0.027	0.035	0.69	0.88
E	0.018	0.023	0.46	0.58
F	0.037	0.045	0.94	1.14
G	0.090 BSC		2.29	BSC
. H	0.034	0.040	0.87	1.01
7	0.018	0.023	0.46	0.58
K	0.350	0.380	8.89	9.65
R	0.180	0.215	4.45	5.45
S	0.025	0.040	0.63	1.01
V	0.035	0.050	0.89	1.27
Z	0.155	44	3.93	

STYLE 1: PIN 1. BASE

COLLECTOR

EMITTER
 COLLECTOR

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